

## BYV26A, BYV26B, BYV26C, BYV26D, BYV26E

**Vishay Semiconductors** 

ROHS COMPLIANT

HALOGEN

FREE

## **Ultra-Fast Avalanche Sinterglass Diode**



#### **MECHANICAL DATA**

Case: SOD-57

**Terminals:** plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

#### Mounting position: any

Weight: approx. 369 mg

#### **FEATURES**

- Glass passivated junction
- Hermetically sealed package
- Very low switching losses
- Low reverse current
- High reverse voltage
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

- Switched mode power supplies
- High-frequency inverter circuits

| ORDERING INFORMATION (Example) |               |                                    |        |  |  |  |
|--------------------------------|---------------|------------------------------------|--------|--|--|--|
| DEVICE NAME                    | ORDERING CODE | TAPED UNITS MINIMUM ORDER QUANTITY |        |  |  |  |
| BYV26E                         | BYV26E-TR     | 5000 per 10" tape and reel         | 25 000 |  |  |  |
| BYV26E                         | BYV26E-TAP    | 5000 per ammopack                  | 25 000 |  |  |  |

| PARTS TABLE |   |         |
|-------------|---|---------|
| PART        | TYPE DIFFERENTIATION                              | PACKAGE |
| BYV26A      | V <sub>R</sub> = 200 V; I <sub>F(AV)</sub> = 1 A  | SOD-57  |
| BYV26B      | V <sub>R</sub> = 400 V; I <sub>F(AV)</sub> = 1 A  | SOD-57  |
| BYV26C      | V <sub>R</sub> = 600 V; I <sub>F(AV)</sub> = 1 A  | SOD-57  |
| BYV26D      | V <sub>R</sub> = 800 V; I <sub>F(AV)</sub> = 1 A  | SOD-57  |
| BYV26E      | V <sub>R</sub> = 1000 V; I <sub>F(AV)</sub> = 1 A | SOD-57  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |        |                    |               |      |  |
|--|--|--------|--------------------|---------------|------|--|
| PARAMETER  | TEST CONDITION                         | PART   | SYMBOL             | VALUE         | UNIT |  |
|  | See electrical characteristics         | BYV26A | $V_{R} = V_{RRM}$  | 200           | V    |  |
| -  |  | BYV26B | $V_{R} = V_{RRM}$  | 400           | V    |  |
| Reverse voltage = repetitive peak reverse<br>voltage                                   |  | BYV26C | $V_{R} = V_{RRM}$  | 600           | V    |  |
| Voltage  |  | BYV26D | $V_{R} = V_{RRM}$  | 800           | V    |  |
|  |  | BYV26E | $V_{R} = V_{RRM}$  | 1000          | V    |  |
| Peak forward surge current   | t <sub>p</sub> = 10 ms, half sine wave |        | I <sub>FSM</sub>   | 30            | А    |  |
| Average forward current  |  |        | I <sub>F(AV)</sub> | 1             | А    |  |
| Non repetitive reverse avalanche energy  | $I_{(BR)R} = 1$ A, inductive load      |        | E <sub>R</sub>     | 10            | mJ   |  |
| Junction and storage temperature range   |  |        | $T_j = T_{stg}$    | - 55 to + 175 | °C   |  |

| <b>MAXIMUM THERMAL RESISTANCE</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |       |      |  |
|--|--|-------------------|-------|------|--|
| PARAMETER  | TEST CONDITION                             | SYMBOL            | VALUE | UNIT |  |
| Junction ambient   | $I = 10 \text{ mm}, T_L = \text{constant}$ | R <sub>thJA</sub> | 45    | K/W  |  |

Rev. 1.8, 04-Sep-12

1



www.vishay.com

**Vishay Semiconductors** 

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |        |                    |      |      |      |      |
|--|---|--------|--------------------|------|------|------|------|
| PARAMETER  | TEST CONDITION  | PART   | SYMBOL             | MIN. | TYP. | MAX. | UNIT |
| Forward voltage  | I <sub>F</sub> = 1 A  |        | V <sub>F</sub>     | -    | -    | 2.5  | V    |
|  | I <sub>F</sub> = 1 A, T <sub>j</sub> = 175 °C                         |        | V <sub>F</sub>     | -    | -    | 1.3  | V    |
| Reverse current  | $V_{R} = V_{RRM}$   |        | I <sub>R</sub>     | -    | -    | 5    | μA   |
|  | V <sub>R</sub> = V <sub>RRM</sub> , T <sub>j</sub> = 150 °C           |        | I <sub>R</sub>     | -    | -    | 100  | μA   |
|  | I <sub>R</sub> = 100 μΑ   | BYV26A | V <sub>(BR)R</sub> | 300  | -    | -    | V    |
|  |   | BYV26B | V <sub>(BR)R</sub> | 500  | -    | -    | V    |
| Reverse breakdown voltage  |   | BYV26C | V <sub>(BR)R</sub> | 700  | -    | -    | V    |
|  |   | BYV26D | V <sub>(BR)R</sub> | 900  | -    | -    | V    |
|  |   | BYV26E | V <sub>(BR)R</sub> | 1100 | -    | -    | V    |
|  | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, i <sub>R</sub> = 0.25 A | BYV26A | t <sub>rr</sub>    | -    | -    | 30   | ns   |
|  |   | BYV26B | t <sub>rr</sub>    | -    | -    | 30   | ns   |
| Reverse recovery time  |   | BYV26C | t <sub>rr</sub>    | -    | -    | 30   | ns   |
|  |   | BYV26D | t <sub>rr</sub>    | -    | -    | 75   | ns   |
|  |   | BYV26E | t <sub>rr</sub>    | -    | -    | 75   | ns   |

TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

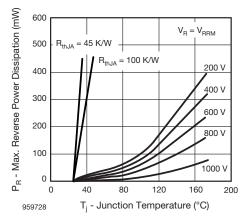


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

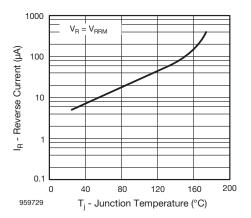


Fig. 2 - Max. Reverse Current vs. Junction Temperature

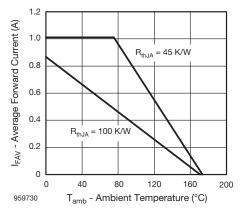


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

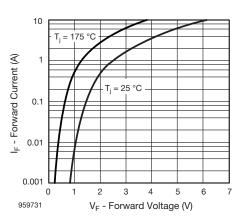


Fig. 4 - Max. Reverse Current vs. Junction Temperature

Rev. 1.8, 04-Sep-12

2

Document Number: 86040

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



### BYV26A, BYV26B, BYV26C, BYV26D, BYV26E

**Vishay Semiconductors** 

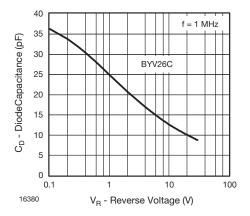


Fig. 5 - Diode Capacitance vs. Reverse Voltage

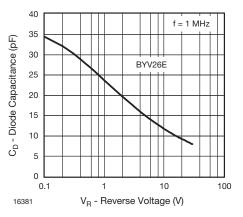
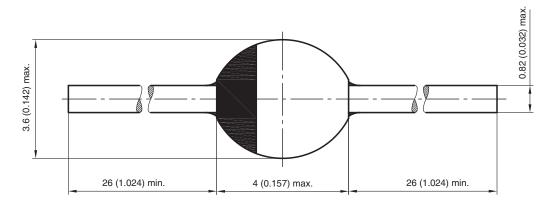


Fig. 6 - Diode Capacitance vs. Reverse Voltage

#### PACKAGE DIMENSIONS in millimeters (inches): SOD-57



20543 Rev. 3 - Date: 09.February 2005 Document no.:6.563-5006.3-4



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.